

## **isc Silicon NPN Power Transistor**

# **BD177**

### DESCRIPTION

- DC Current Gain-
  - : h<sub>FE</sub>= 40-250(Min)@ I<sub>C</sub>= 0.15A
- Collector-Emitter Sustaining Voltage -
- : V<sub>CEO(SUS)</sub>= 60V(Min)
- Complement to type BD178
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATIONS

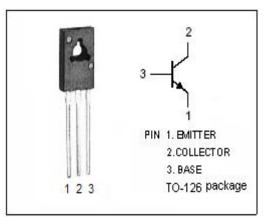
Designed for medium power linear and switching applications.

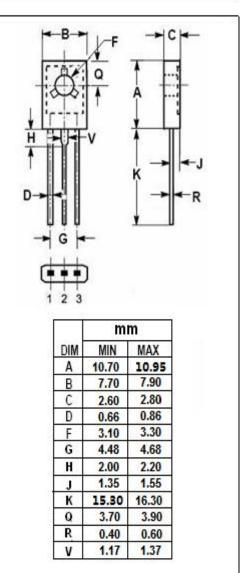
### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	60	v
V <sub>CEO</sub>	Collector-Emitter Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
lc	Collector Current-Continuous	3	А
I <sub>CM</sub>	Collector Current-Pulse	7	А
Pc	Collector Power Dissipation @ $T_c=25^{\circ}C$	30	W
TJ	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-65~150	°C

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	8.5	°C/W
R <sub>th j-a</sub>	Thermal Resistance, Junction to Ambient	70	°C/W





isc website: www.iscsemi.com



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### **ELECTRICAL CHARACTERISTICS**

#### T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	мах	UNIT
Vceo(sus)	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 50mA ; I <sub>B</sub> = 0	60			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1A; I <sub>B</sub> = 0.1A			0.8	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 1A; V <sub>CE</sub> = 2V			1.3	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 60V; I <sub>E</sub> = 0			100	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 150mA; V <sub>CE</sub> = 2V	40		250	
h <sub>FE-2</sub>	DC Current Gain	Ic= 1A; Vc== 2V	15			
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.25A; V <sub>CE</sub> = 10V	3			MHz

#### h<sub>FE-1</sub> Classifications

6	10	16	
40-100	63-160	100-250	

### **NOTICE:**

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